



Dual N-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)			
20	0.280 at V _{GS} = 4.5 V	1.28			
	0.360 at V _{GS} = 2.5 V	1.13			
	0.450 at V _{GS} = 1.8 V	1.0			

FEATURES

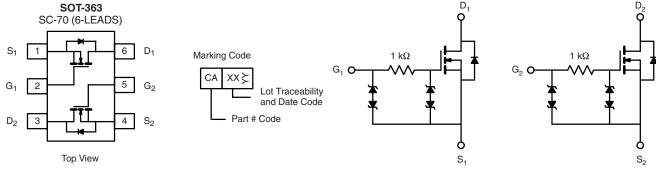
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFETs: 1.8 V Rated
- ESD Protected: 2000 V
- Thermally Enhanced SC-70 Package
- Compliant to RoHS Directive 2002/95/EC



ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

- Load Switching
- PA Switch
- · Level Switch



Ordering Information: Si1912EDH-T1-E3 (Lead (Pb)-free)

Si1912EDH-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter	Symbol	5 s	Steady State	Unit	
Drain-Source Voltage	V _{DS}	20		V	
Gate-Source Voltage		V _{GS}	± 12		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	,	1.28	1.13	- A
	T _A = 85 °C	l ID	0.92	0.81	
Pulsed Drain Current		I _{DM}	4		
Continuous Diode-Current (Diode Conduction) ^a		I _S	0.61	0.48	
Maximum Power Dissipation ^a	T _A = 25 °C	- P _D -	0.74	0.57	W
iviaximum rower Dissipation	T _A = 85 °C		0.38	0.30	
Operating Junction and Storage Temperature Range		T _J , T _{stq}	- 55	to 150	°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	t ≤ 5 s	- R _{thJA}	130	170		
	Steady State		170	220	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	80	100		

Notes:

a. Surface mounted on 1" x 1" FR4 board.



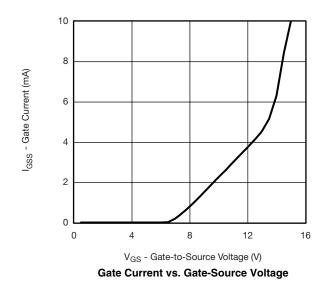
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static			•	•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_{D} = 100 \mu A$	0.45			V	
Oata Bada Laskana		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			± 1	μΑ	
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 12 V			± 10	mA	
Zava Cata Valtaga Dvain Curvent	,	V _{DS} = 16 V, V _{GS} = 0 V			1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 16 V, V _{GS} = 0 V, T _J = 85 °C			5		
On-State Drain Current ^a	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 4.5 V	2			Α	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 1.13 A		0.220	0.280		
		V _{GS} = 2.5 V, I _D = 0.99 A		0.281	0.360	Ω	
		V _{GS} = 1.8 V, I _D = 0.2 A		0.344	0.450		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 1.13 A		2.6		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 0.48 A, V _{GS} = 0 V		0.8	1.2	V	
Dynamic ^b							
Total Gate Charge	Q_g			0.65	1		
Gate-Source Charge	Q _{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 1.13 \text{ A}$		0.2		nC	
Gate-Drain Charge	Q _{gd}			0.23			
Turn-On Delay Time	t _{d(on)}			45	70		
Rise Time	t _r	$V_{DD} = 10 \text{ V}, R_{L} = 20 \Omega$		85	130		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 0.5 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 6 \Omega$		350	530	ns	
Fall Time	t _f			210	320		

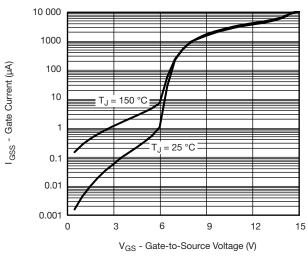
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





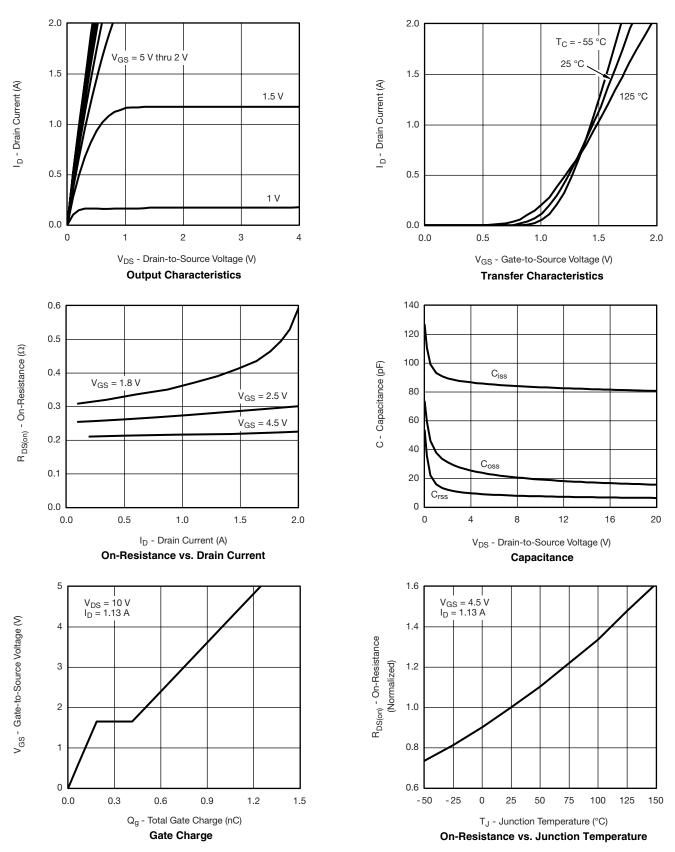
Gate Current vs. Gate-Source Voltage





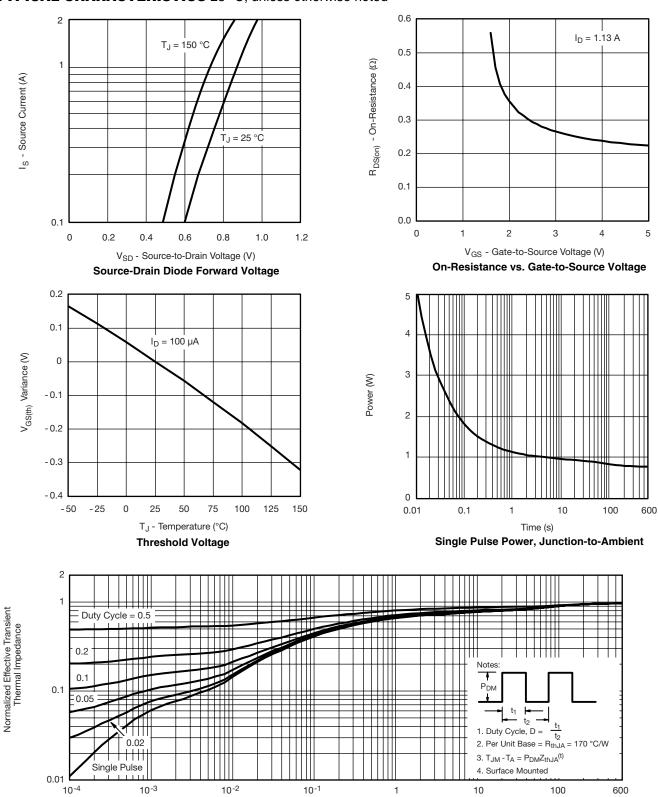


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



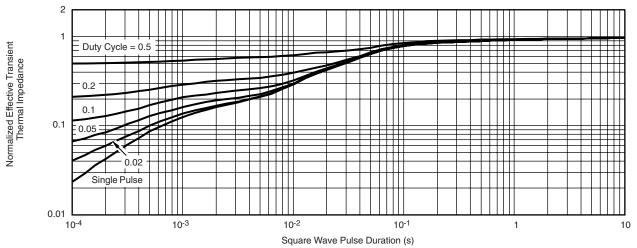
VISHAY

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



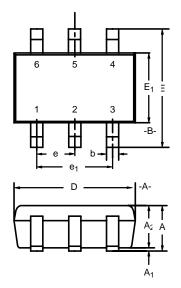
Normalized Thermal Transient Impedance, Junction-to-Foot

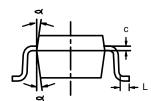
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg271408.





SC-70: 6-LEADS





Min 0.90 - 0.80	Nom - -	1.10 0.10	Min 0.035	Nom -	Max 0.043
_	-		0.035	_	0.043
- 0.80	-	0.10			0.040
0.80			_	_	0.004
	-	1.00	0.031	_	0.039
0.15	-	0.30	0.006	_	0.012
0.10	_	0.25	0.004	-	0.010
1.80	2.00	2.20	0.071	0.079	0.087
1.80	2.10	2.40	0.071	0.083	0.094
1.15	1.25	1.35	0.045	0.049	0.053
0.65BSC				0.026BSC	;
1.20	1.30	1.40	0.047	0.051	0.055
0.10	0.20	0.30	0.004	0.008	0.012
7°Nom 7°Nom					
	0.10 1.80 1.80 1.15 1.20 0.10	0.10	0.10 - 0.25 1.80 2.00 2.20 1.80 2.10 2.40 1.15 1.25 1.35 0.65BSC 1.20 1.30 1.40 0.10 0.20 0.30 7°Nom	0.10	0.10

DWG: 5550

Document Number: 71154 www.vishay.com 06-Jul-01 sww.vishay.com



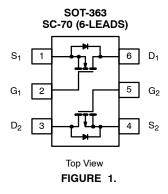
Dual-Channel LITTLE FOOT® 6-Pin SC-70 MOSFET Copper Leadframe Version Recommended Pad Pattern and Thermal Performance

INTRODUCTION

The new dual 6-pin SC-70 package with a copper leadframe enables improved on-resistance values and enhanced thermal performance as compared to the existing 3-pin and 6-pin packages with Alloy 42 leadframes. These devices are intended for small to medium load applications where a miniaturized package is required. Devices in this package come in a range of on-resistance values, in n-channel and p-channel versions. This technical note discusses pin-outs, package outlines, pad patterns, evaluation board layout, and thermal performance for the dual-channel version.

PIN-OUT

Figure 1 shows the pin-out description and Pin 1 identification for the dual-channel SC-70 device in the 6-pin configuration. Both n-and p-channel devices are available in this package — the drawing example below illustrates the p-channel device.



For package dimensions see outline drawing SC-70 (6-Leads) (http://www.vishay.com/doc?71154)

BASIC PAD PATTERNS

See Application Note 826, Recommended Minimum Pad Patterns With Outline Drawing Access for Vishay Siliconix MOSFETs, (http://www.vishay.com/doc?72286) for the SC-70 6-pin basic pad layout and dimensions. This pad pattern is sufficient for the low-power applications for which this package is intended. Increasing the drain pad pattern (Figure 2) yields a reduction in thermal resistance and is a preferred footprint.

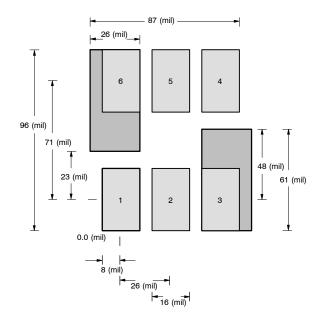


FIGURE 2. SC-70 (6 leads) Dual

EVALUATION BOARD FOR THE DUAL-CHANNEL SC70-6

The 6-pin SC-70 evaluation board (EVB) shown in Figure 3 measures 0.6 in. by 0.5 in. The copper pad traces are the same as described in the previous section, *Basic Pad Patterns*. The board allows for examination from the outer pins to the 6-pin DIP connections, permitting test sockets to be used in evaluation testing.

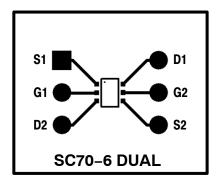
The thermal performance of the dual 6-pin SC-70 has been measured on the EVB, comparing both the copper and Alloy 42 leadframes. This test was then repeated using the 1-inch² PCB with dual-side copper coating.

A helpful way of displaying the thermal performance of the 6-pin SC-70 dual copper leadframe is to compare it to the traditional Alloy 42 version.

Document Number: 71405 www.vishay.com



Front of Board SC70-6



Back of Board SC70-6

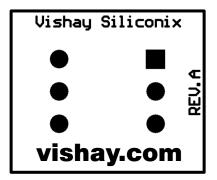


FIGURE 3.

THERMAL PERFORMANCE

Junction-to-Foot Thermal Resistance (the Package Performance)

Thermal performance for the dual SC-70 6-pin package is measured as junction-to-foot thermal resistance, in which the "foot" is the drain lead of the device as it connects with the body. The junction-to-foot thermal resistance for this device is typically 80°C/W, with a maximum thermal resistance of approximately 100°C/W. This data compares favorably with another compact, dual-channel package – the dual TSOP-6 – which features a typical thermal resistance of 75°C/W and a maximum of 90°C/W.

Power Dissipation

The typical $R\theta_{JA}$ for the dual-channel 6-pin SC-70 with a copper leadframe is 224°C/W steady-state, compared to 413°C/W for the Alloy 42 version. All figures are based on the 1-inch² FR4 test board. The following example shows how the thermal resistance impacts power dissipation for the dual 6-pin SC-70 package at varying ambient temperatures.

Alloy 42 Leadframe

ALLOY 42 LEADFRAME				
Room Ambient 25 °C	Elevated Ambient 60 °C			
$P_D = \frac{T_{J(max)} - T_A}{R\theta_{JA}}$	$P_D = \frac{T_{J(max)} - T_A}{R\theta_{JA}}$			
$P_{D} = \frac{150^{\circ}C - 25^{\circ}C}{413^{\circ}C/W}$	$P_{D} = \frac{150^{\circ}C - 60^{\circ}C}{413^{\circ}C/W}$			
$P_D = 303 \text{ mW}$	$P_D = 218 \text{ mW}$			

COOPER LEADFRAME				
Room Ambient 25 °C	Elevated Ambient 60 °C			
$P_D = \frac{T_{J(max)} - T_A}{R\theta_{JA}}$	$P_D = \frac{T_{J(max)} - T_A}{R\theta_{JA}}$			
$P_{D} = \frac{150^{\circ}C - 25^{\circ}C}{224^{\circ}C/W}$	$P_{D} = \frac{150^{\circ}C - 60^{\circ}C}{224^{\circ}C/W}$			
$P_D = 558 \text{ mW}$	$P_D = 402 \text{mW}$			

Although they are intended for low-power applications, devices in the 6-pin SC-70 dual-channel configuration will handle power dissipation in excess of 0.5 W.

TESTING

To further aid the comparison of copper and Alloy 42 leadframes, Figures 4 and 5 illustrate the dual-channel 6-pin SC-70 thermal performance on two different board sizes and pad patterns. The measured steady-state values of $R\theta_{JA}$ for the dual 6-pin SC-70 with varying leadframes are as follows:

LITTLE FOOT 6-PIN SC-70					
	Alloy 42	Copper			
Minimum recommended pad pattern on the EVB board (see Figure 3).	518°C/W	344°C/W			
Industry standard 1-inch ² PCB with maximum copper both sides.	413°C/W	224°C/W			

The results indicate that designers can reduce thermal resistance (θ JA) by 34% simply by using the copper leadframe device as opposed to the Alloy 42 version. In this example, a 174°C/W reduction was achieved without an increase in board area. If an increase in board size is feasible, a further 120°C/W reduction can be obtained by utilizing a 1-inch². PCB area.

The Dual copper leadframe versions have the following suffix:

Dual: Si19xxEDH Compl.: Si15xxEDH

Document Number: 71405

...

2

www.vishay.com





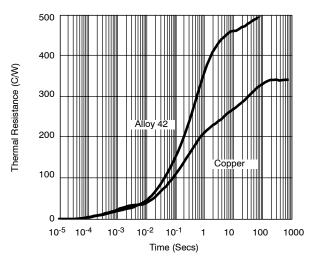


FIGURE 4. Dual SC70-6 Thermal Performance on EVB

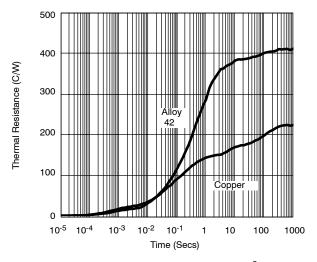
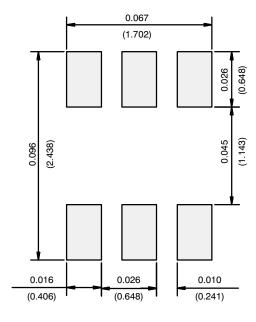


FIGURE 5. Dual SC70-6 Comparison on 1-inch² PCB



RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.